Features and Benefits

Less than ±1E-12 Allan deviation for tau=1 second Less than ±1 ppb stability over -40°C to +85°C Rugged 50 x 50 mm enclosure

Typical Applications

Ideal clock for high performance SATCOM ground stations Test Instrument reference oscillator Clock for high performance synthesizers

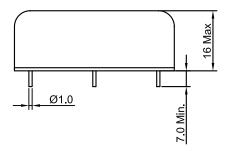
Description

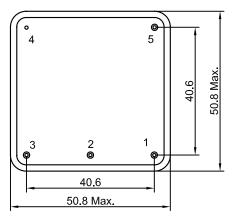
Use of low noise resonator processing techniques to deliver ultra-high Q 10 MHz SC-cuts which are needed to offer superior close-in noise / Allan deviation performance OCXO's.

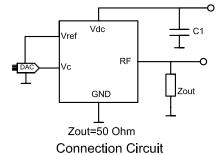
Mechanical Drawing & Pin Connections

Drawing No: MD1

MD170010-1







Pin Connections:

Pin#	Symbol	Function			
1	Vc	Control Voltage			
2	Vref	Reference Output (4.5V)			
3	RF Out	RF Output			
4	GND	Ground			
5	Vdc	Supply Voltage			

Unit in mm 1mm = 0.0394 inches



Dynamic Engineers Inc.

OCXO5050Z-10MHz-C-V ÉÍ XÂĴ] ^{嶺 ¦Á笕爾碑 ÁĈ^ç霞ᡂ } ÁĴÔÝUÁ

2550 Gray Falls Dr., Suite#128, Houston, TX, 77077 USA TEL: 1-281-870-8822 EMAIL: Sales@DynamicEng.com

Oscillator	Sym	Condition	Value			Unit	Note
Specification			Min.	Тур.	Max.	Unit	Note
Nominal Frequency	f_0		10.000000			MHz	
Waveform		+3dBm ±1 dBm	Sine wave				
Output Load		±5%		50		Ω	
Power Supply	•			,			
Supply Voltage	V_{CC}	±5%		+5		V	
Warm-up Time for <±2 x 10 ⁻⁸	t_{up}	@+25°C		<3		min	
Current During Warm-up time				<1500		mA	
Consumption Steady-state				<500		mA	
Frequency Control							
Frequency Pulling Range		Positive slope		>±0.4		ppm	
Electronic Frequency Control (EFC)			0		+4.5	V	
Reference Voltage Output	V_{ref}			+4.5		V	
Frequency Stability							
Vs. Operating Temperature Range		Over -40°C ~ +85°C		±1		ppb	
Vs.Supply Voltage Change		±5%		±0.5		ppb	
Vs. Load Change		±5%		±0.5		ppb	
Aging Per Day		After 30 days of		±1		ppb	
i yeai		operation		±30		ppb	
Short term Stability (Allan deviation)		Tau = 1s		0.001		ppb	
		1 Hz		<-95		dBc/Hz	
Phase Noise @ 10 MHz carrier		10 Hz		<-125			
frequency		100 Hz		<-145			
nequency		1 kHz		<-150			
		10 kHz		<-155			
Harmonics Suppression				>30		dBc	
Operating Temperature		o +85°C					
Storage Temperature	-55°C t	o +105°C				·	, and the second

D/fZcfa UbW; fUb/ giox cfHYfa glu/j]mz5 UbX/j]U]dbQ

